

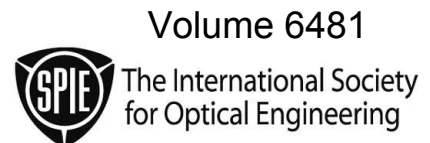
PROCEEDINGS OF SPIE

# ***Quantum Dots, Particles, and Nanoclusters IV***

**Kurt G. Eyink  
Diana L. Huffaker  
Frank Szmulowicz**  
*Editors*

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